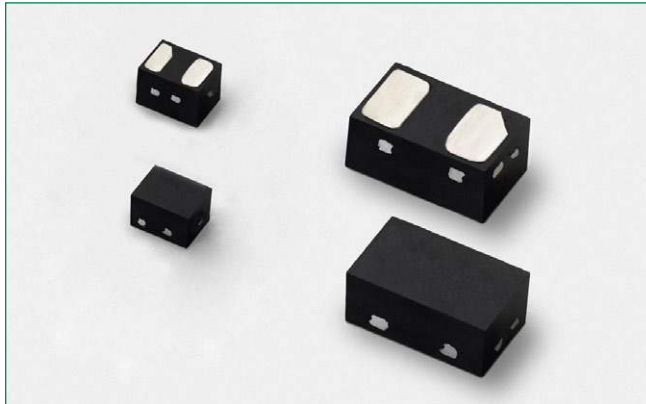
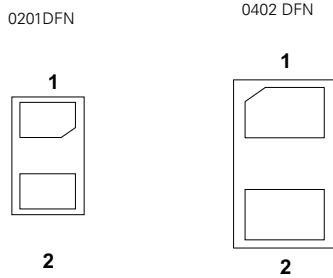


SESD Series Ultra Low Capacitance Discrete TVS



Pinout



Bottom View

Functional Block Diagram



Unidirectional

Bidirectional

Description

The SESD Series Ultra Low Capacitance Discrete TVS provides unidirectional and bidirectional ESD protection for the most challenging high speed serial interfaces. Its low off-state capacitance, extremely low leakage (< 50 nA) and low dynamic resistance make it compatible with high speed signaling such as USB 3.1, HDMI 2.0, DisplayPort, and V-by-One®.

The SESD series has an ESD (IEC 61000-4-2) rating of ±20 kV packaged in the industry's popular 0402 and 0201 footprints.

Features

- 0.13pF MAX bidirectional off-state capacitance
- 0.25pF MAX unidirectional off-state capacitance
- IEC 61000-4-2 ESD rating of ±20 kV air and contact discharge
- Low clamping voltage of 10V @ IPP=2A (Bidirectional) (tP=8/20µs)
- PPAP capable
- Low profile 0201 and 0402 DFN packages
- Facilitates excellent signal integrity
- ELV-Compliant
- RoHS-Compliant and Lead-Free

Applications

- Ultra-high speed data lines
- USB 3.1, 3.0, 2.0
- HDMI 2.0, 1.4a, 1.3
- DisplayPort™
- Thunderbolt (Light Peak)
- V-by-One®
- LVDS interfaces
- Consumer, mobile and portable electronics
- Tablet PC and external storage with high speed interfaces
- Applications requiring high ESD performance in small packages

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I_{PP}	Peak Current ($t_p=8/20\mu s$)	2.0	A
T_{OP}	Operating Temperature	-55 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

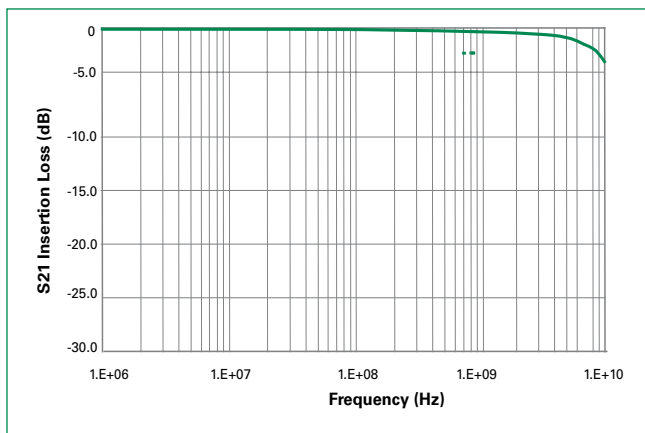
Unidirectional Electrical Characteristics - ($T_{OP}=25^\circ C$)

Parameter	Test Conditions	Min	Typ	Max	Units
Input Capacitance	Reverse Bias=0V, f = 3GHz	-	0.20	0.25	pF
Breakdown Voltage	V_{BR} @ $I_T=1mA$	-	9.00	-	V
Reverse Working Voltage	-	-	-	7.0	V
Reverse Leakage Current	I_L @ $V_{RWM}=5.0V$	-	25	50	nA
Clamping Voltage	V_{CL} @ $I_{PP}=2.0A$	-	9.20	-	V
ESD Withstand Voltage	IEC 61000-4-2 (Contact)	±20	-	-	kV
	IEC 61000-4-2 (Air)	±20	-	-	

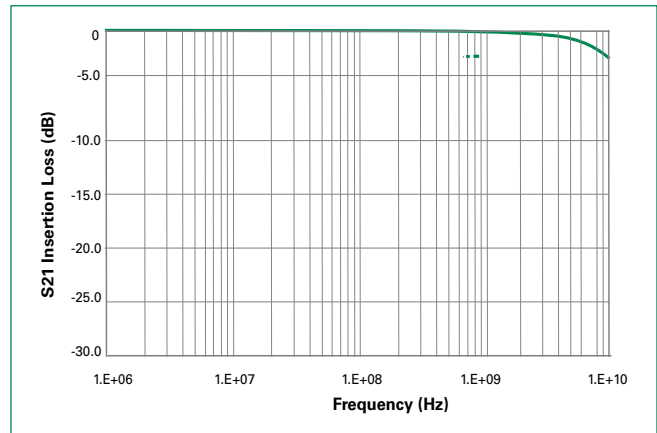
Bidirectional Electrical Characteristics - ($T_{OP}=25^\circ C$)

Parameter	Test Conditions	Min	Typ	Max	Units
Input Capacitance	Reverse Bias=0V, f = 3GHz	-	0.10	0.13	pF
Breakdown Voltage	V_{BR} @ $I_T=1mA$	-	9.80	-	V
Reverse Working Voltage	-	-	-	7.0	V
Reverse Leakage Current	I_L @ $V_{RWM}=5.0V$	-	25	50	nA
Clamping Voltage	V_{CL} @ $I_{PP}=2.0A$	-	10.0	-	V
ESD Withstand Voltage	IEC 61000-4-2 (Contact)	±20	-	-	kV
	IEC 61000-4-2 (Air)	±20	-	-	

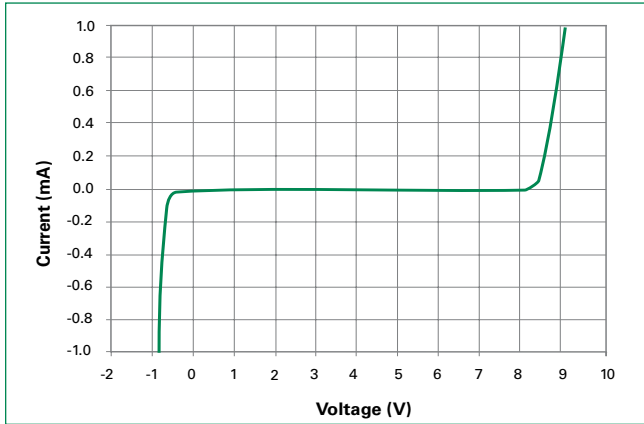
Insertion Loss Diagram - Unidirectional



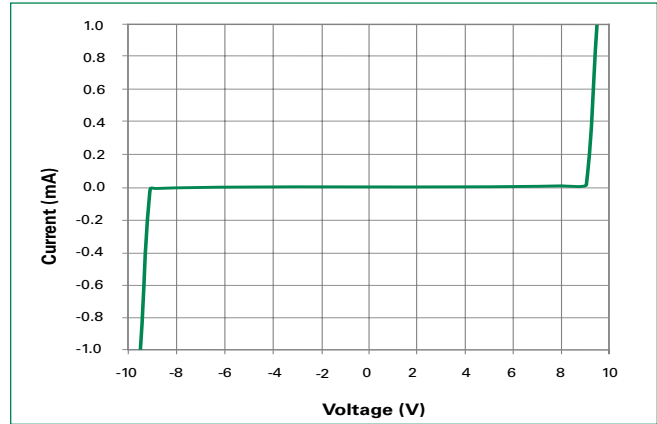
Insertion Loss Diagram - Bidirectional



Component IV Curve - Unidirectional

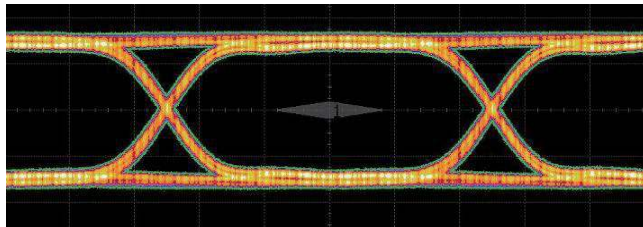


Component IV Curve - Bidirectional

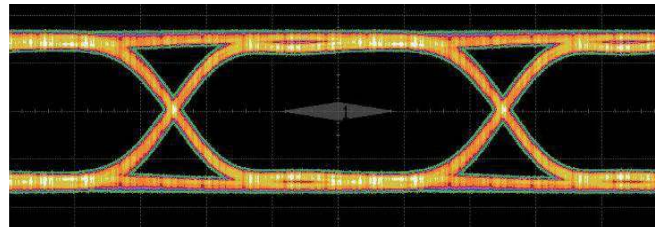


USB3.0 Eye Diagram

5.0 Gb/s, 1000mV differential, CPO Compliant Test Pattern



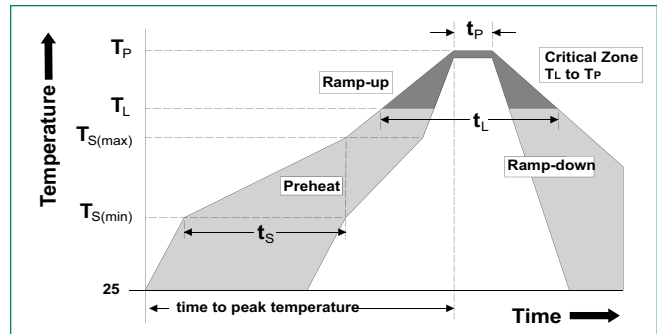
Without SESD Device



With SESD Device

Soldering Parameters

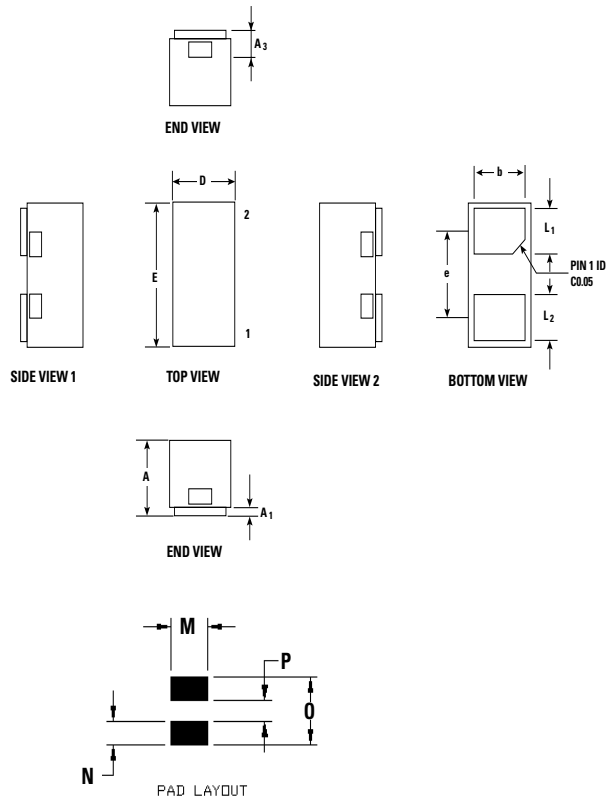
Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Product Characteristics

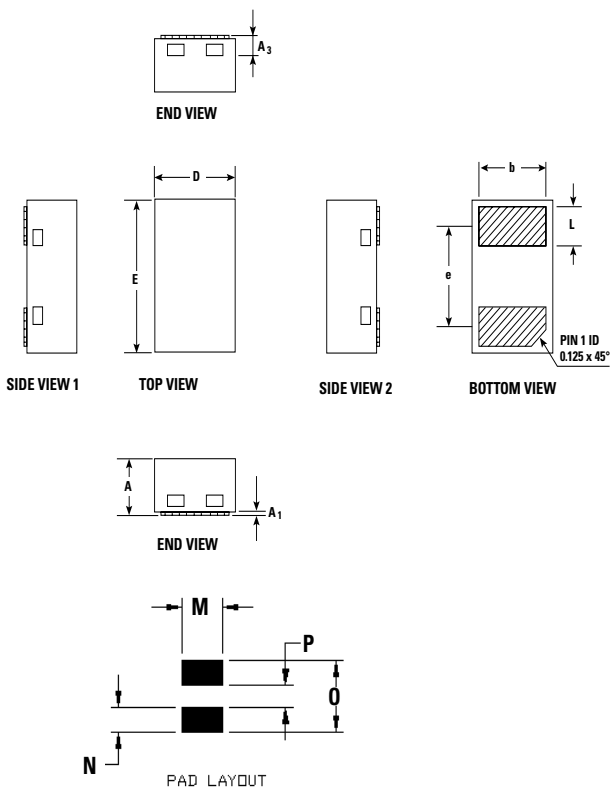
Lead Plating	Pre-Plated Frame
Lead Material	Copper Alloy
Substrate material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0

Package Dimensions — 0201 DFN



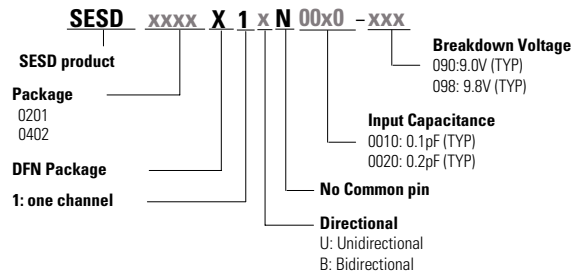
Symbol	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	0.28	0.30	0.32	0.011	0.012	0.013
A1	0	-	0.05	0	-	0.002
A3	0.102 ref.			0.004 ref.		
D	0.25	0.30	0.35	0.010	0.012	0.014
E	0.55	0.60	0.65	0.022	0.024	0.026
b	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.13	0.18	0.23	0.005	0.008	0.009
L2	0.14	0.19	0.24	0.006	0.007	0.009
e	0.356 BSC			0.014 BSC		
M		0.32			0.013	
N		0.24			0.009	
O		0.62			0.024	
P		0.14			0.006	

Package Dimensions — 0402 DFN

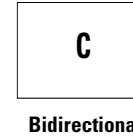
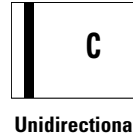


Symbol	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	0.31	0.38	0.43	0.013	0.015	0.017
A1	0	-	0.05	0	-	0.002
A3	0.13 ref.			0.005 ref.		
D	0.55	0.60	0.65	0.022	0.024	0.026
E	0.95	1.00	1.05	0.037	0.039	0.041
b	0.45	0.50	0.55	0.018	0.020	0.022
L	0.20	0.25	0.30	0.008	0.010	0.012
e	0.65 BSC			0.026 BSC		
M		0.60			0.024	
N		0.35			0.014	
O		1.00			0.039	
P		0.30			0.012	

Part Numbering System



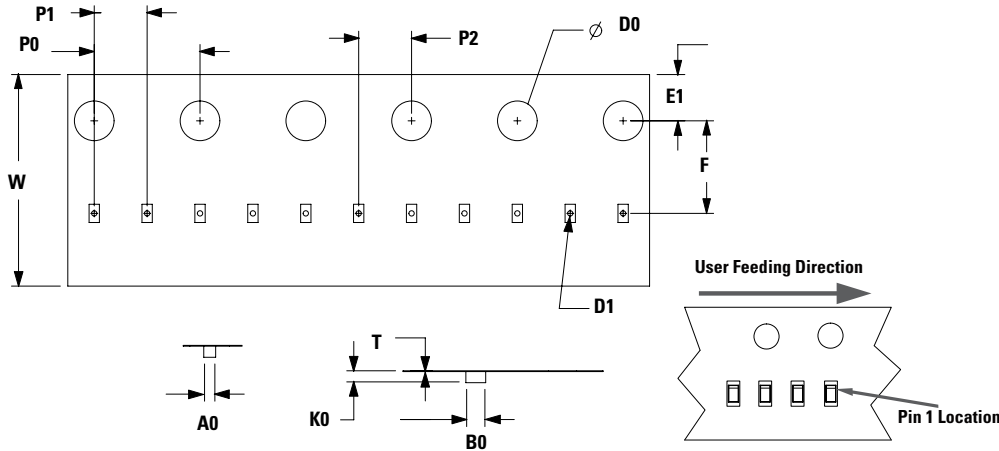
Part Marking System



Ordering Information

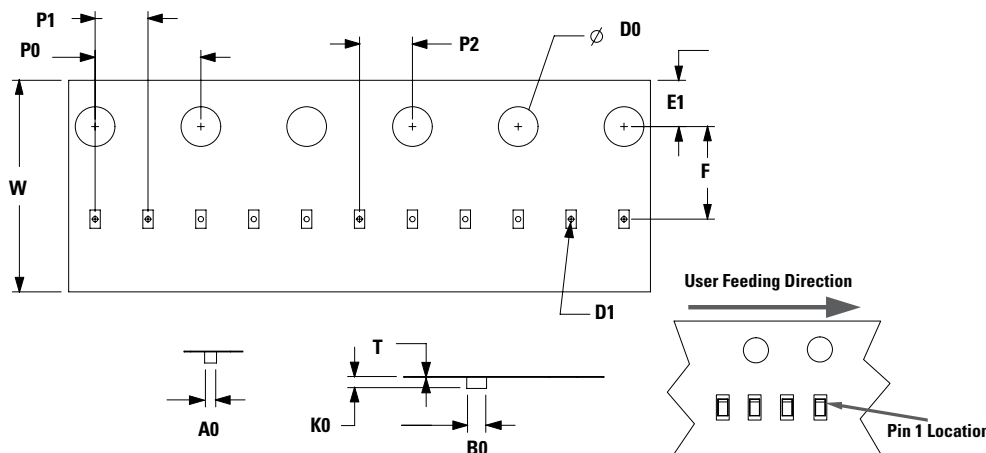
Part Number	Package	Ordering Part Number	Min. Order Qty.
SESD0201X1UN-0020-090	0201 DFN	RF2192-000	75000
SESD0201X1BN-0010-098	0201 DFN	RF2193-000	75000
SESD0402X1UN-0020-090	0402 DFN	RF2943-000	50000
SESD0402X1BN-0010-098	0402 DFN	RF2945-000	50000

Embossed Carrier Tape & Reel Specification – 0201 DFN



Symbol	Millimeters
A0	0.36+/-0.03
B0	0.66+/-0.03
D0	ø 1.50 +0.10/-0
D1	ø 0.20 +/- 0.05
E1	1.75+/-0.10
F	3.50+/-0.05
K0	0.33+/-0.03
P0	4.00+/-0.10
P1	2.00+/-0.10
P2	2.00+/-0.05
W	8.00+/-0.10
T	0.23+/-0.02

Embossed Carrier Tape & Reel Specification – 0402 DFN



Symbol	Millimeters
A0	0.70+/-0.05
B0	1.15+/-0.05
D0	ø 1.55 + 0.05
D1	ø 0.40 +/- 0.05
E1	1.75+/-0.10
F	3.50+/-0.05
K0	0.47+/-0.05
P0	4.00+/-0.10
P1	2.00+/-0.10
P2	2.00+/-0.05
W	8.00+/-0.10
T	0.20+/-0.05